

CD4078B Types

CMOS 8-Input NOR/OR Gate

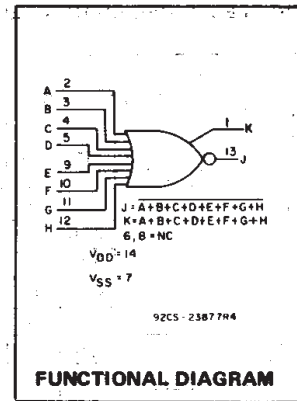
High-Voltage Types (20-Volt Rating)

■ CD4078B NOR/OR Gate provides the system designer with direct implementation of the positive-logic 8-input NOR and OR functions and supplements the existing family of CMOS gates.

The CD4078B types are supplied in 14-lead dual-in-line ceramic packages (D and F suffixes), 14-lead dual-in-line plastic packages (E suffix), and in chip form (H suffix).

Features:

- Medium-Speed Operation:
t_{PHL}, t_{PLH} = 75 ns (typ.) at V_{DD} = 10 V
- Buffered inputs and output
- 5-V, 10-V, and 15-V parametric ratings
- Standardized symmetrical output characteristics
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 μA at 18 V over full package-temperature range: 100 nA at 18 V and 25°C
- Noise margin (over full package-temperature range):
1 V at V_{DD} = 5 V
2 V at V_{DD} = 10 V 2.5 V at V_{DD} = 15 V
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"



FUNCTIONAL DIAGRAM

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (V_{DD})

Voltages referenced to V_{SS} Terminal -0.5V to +20V

INPUT VOLTAGE RANGE, ALL INPUTS -0.5V to V_{DD} +0.5V

DC INPUT CURRENT, ANY ONE INPUT ±10mA

POWER DISSIPATION PER PACKAGE (P_D):

For T_A = -55°C to +100°C 500mW

For T_A = +100°C to +125°C Derate Linearly at 12mW/°C to 200mW

DEVICE DISSIPATION PER OUTPUT TRANSISTOR

FOR T_A = FULL PACKAGE-TEMPERATURE RANGE (All Package Types) 100mW

OPERATING-TEMPERATURE RANGE (T_A) -55°C to +125°C

STORAGE TEMPERATURE RANGE (T_{stg}) -65°C to +150°C

LEAD TEMPERATURE (DURING SOLDERING):

At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm) from case for 10s max +265°C

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	Min.	Max.	Units
Supply Voltage Range (For T _A Full Package Temperature Range)	3	18	V

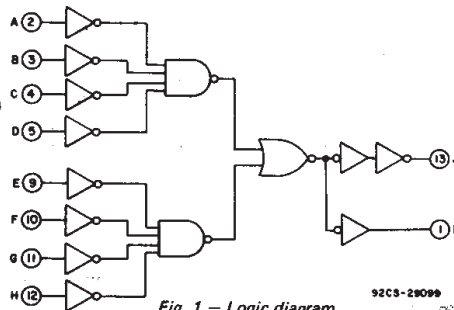


Fig. 1 - Logic diagram.

DYNAMIC ELECTRICAL CHARACTERISTICS

At T_A = 25°C; Input t_r, t_f = 20 ns, C_L = 50 pF, R_L = 200kΩ

CHARACTERISTIC	TEST CONDITIONS	LIMITS		UNITS	
		V _{DD} VOLTS	TYP.		MAX.
Propagation Delay Time, t _{PHL} , t _{PLH}		5	150	300	ns
		10	75	150	
		15	55	110	
Transition Time, t _{THL} , t _{TLH}		5	100	200	ns
		10	50	100	
		15	40	80	
Input Capacitance, C _{I(N)}	Any Input		5	7.5	pF

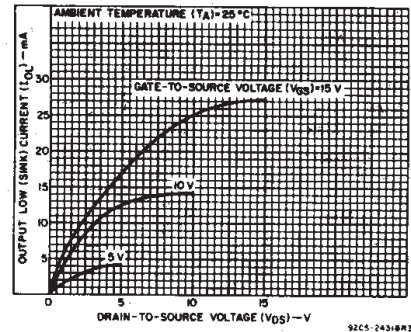


Fig. 2 - Typical output low (sink) current characteristics.

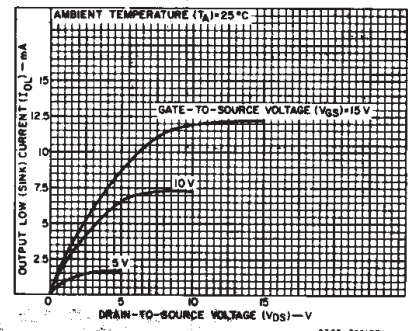


Fig. 3 - Minimum output low (sink) current characteristics.

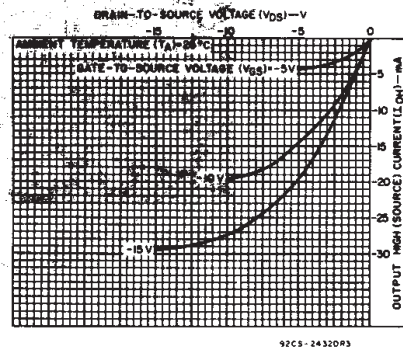


Fig. 4 - Typical output high (source) current characteristics.

CD4078B Types

STATIC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							UNITS
	V _O (V)	V _{IN} (V)	V _{DD} (V)	+25							
				-55	-40	+85	+125	Min.	Typ.	Max.	
Quiescent Device Current, I _{DD} Max.	-	0,5	5	0.25	0.25	7.5	7.5	-	0.01	0.25	μA
	-	0,10	10	0.5	0.5	15	15	-	0.01	0.5	
	-	0,15	15	1	1	30	30	-	0.01	1	
	-	0,20	20	5	5	150	150	-	0.02	5	
Output Low (Sink) Current, I _{OL} Min.	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1		mA
	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6		
	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8		
Output High (Source) Current, I _{OH} Min.	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1		mA
	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2		
	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6		
Output Voltage, Low Level, V _{OL} Max.	-	0,5	5			0.05			0	0.05	V
	-	0,10	10			0.05			0	0.05	
	-	0,15	15			0.05			0	0.05	
Output Voltage, High Level, V _{OH} Min.	-	0,5	5			4.95		4.95	5		V
	-	0,10	10			9.95		9.95	10		
	-	0,15	15			14.95		14.95	15		
Input Low Voltage, V _{IL} Max.	0.5, 4.5	-	5			1.5		-	-	1.5	V
	1.9	-	10			3		-	-	3	
	1.5, 13.5	-	15			4		-	-	4	
Input High Voltage, V _{IH} Min.	0.5, 4.5	-	5			3.5		3.5	-	-	V
	1.9	-	10			7		7	-	-	
	1.5, 13.5	-	15			11		11	-	-	
Input Current, I _{IN} Max.		0.18	18	±0.1	±0.1	±1	±1	-	±10 ⁻⁵	±0.1	μA

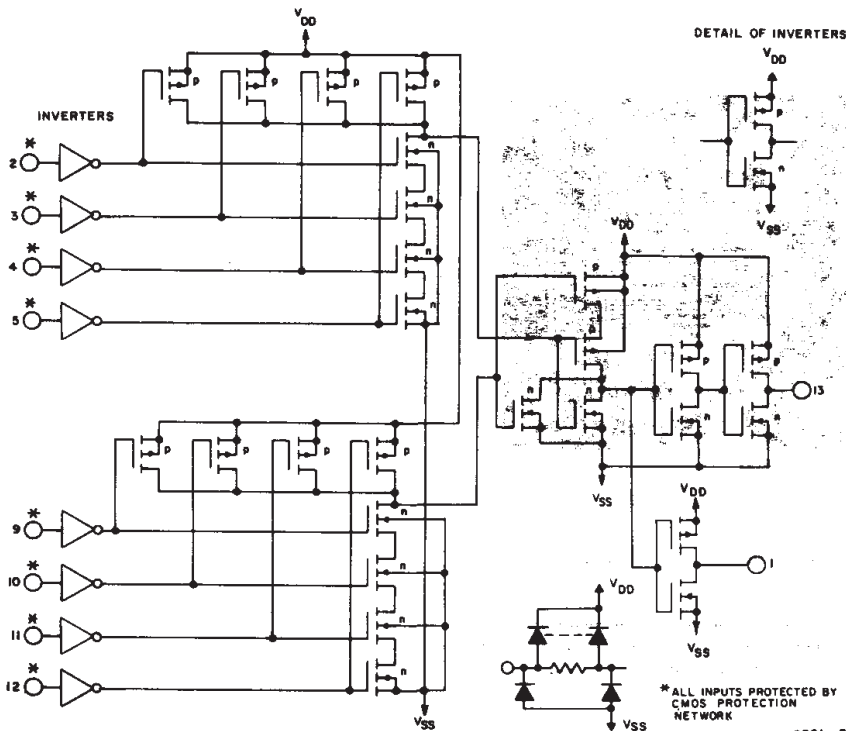


Fig. 8 - Schematic diagram.

92CL-29098

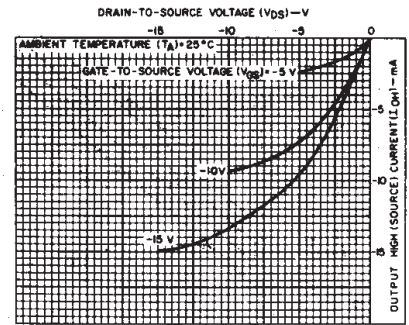


Fig. 5 - Minimum output high (source) current characteristics.

92CS-24321R2

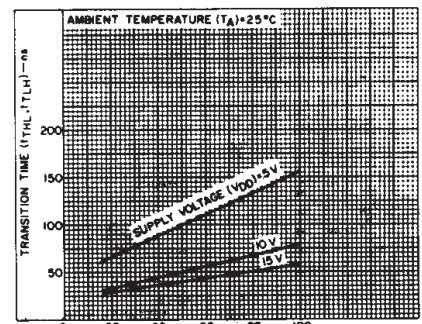


Fig. 6 - Typical transition time as a function of load capacitance.

92CS-24322

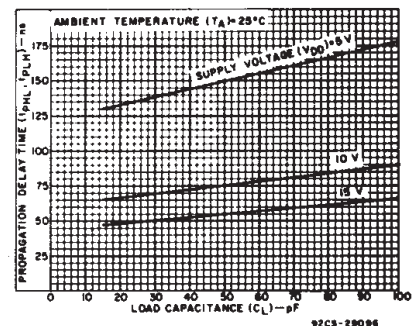


Fig. 7 - Typical propagation delay time as a function of load capacitance.

92CS-29094

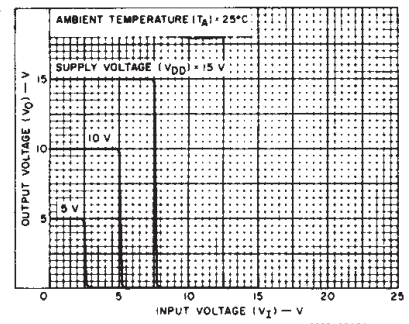


Fig. 9 - Typical voltage transfer characteristics (NOR output).

92CS-26904

3
COMMERCIAL CMOS
HIGH VOLTAGE ICs

CD4078B Types

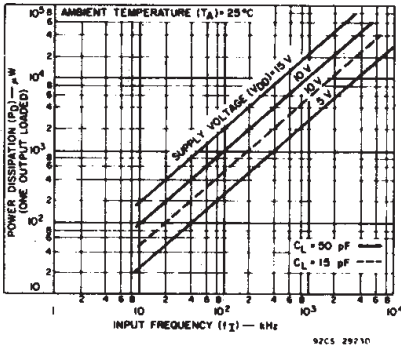


Fig. 10 — Typical dynamic power dissipation as a function of frequency.

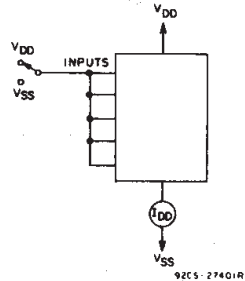


Fig. 11 — Quiescent-device-current test circuit.

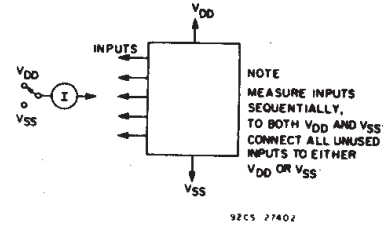


Fig. 12 — Input current test circuit.

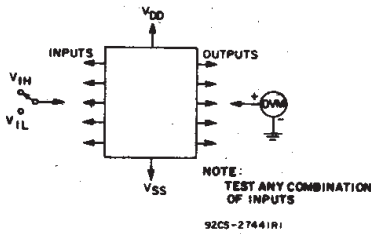


Fig. 13 — Input-voltage test circuit.

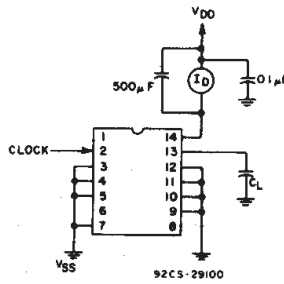
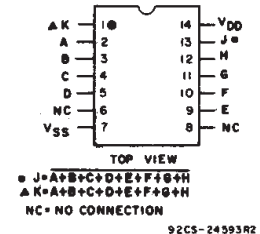
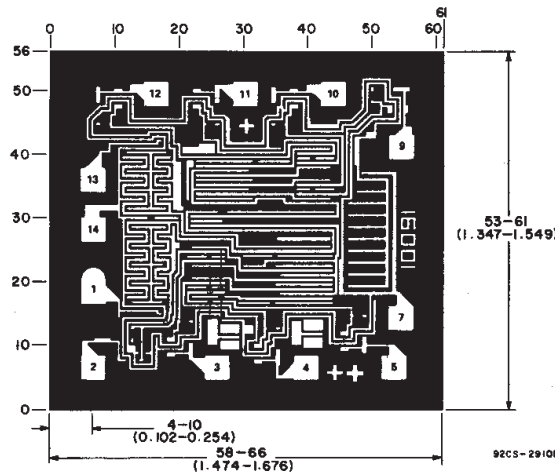


Fig. 14 — Dynamic power dissipation test circuit.



TERMINAL ASSIGNMENT



Dimensions and pad layout for CD4078BH.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

IMPORTANT NOTICE

Texas Instruments and its subsidiaries (TI) reserve the right to make changes to their products or to discontinue any product or service without notice, and advise customers to obtain the latest version of relevant information to verify, before placing orders, that information being relied on is current and complete. All products are sold subject to the terms and conditions of sale supplied at the time of order acknowledgement, including those pertaining to warranty, patent infringement, and limitation of liability.

TI warrants performance of its semiconductor products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

CERTAIN APPLICATIONS USING SEMICONDUCTOR PRODUCTS MAY INVOLVE POTENTIAL RISKS OF DEATH, PERSONAL INJURY, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE ("CRITICAL APPLICATIONS"). TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS. INCLUSION OF TI PRODUCTS IN SUCH APPLICATIONS IS UNDERSTOOD TO BE FULLY AT THE CUSTOMER'S RISK.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards must be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance or customer product design. TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used. TI's publication of information regarding any third party's products or services does not constitute TI's approval, warranty or endorsement thereof.